# RMDXM SERIES

## MINIATURE SINGLE-PHASE BRIDGE RECTIFIER

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## RMD1M THRU RMD7M

#### MINIATURE GLASS PASSIVATED FAST RECOVERY SINGLE-PHASE BRIDGE RECTIFIER



REVERSE VOLTAGE: FORWARD CURRENT:

50 to 1000 VOLTS 0.5 AMPERE

#### **FEATURES**

· Glass passivated chip junction

· Fast recovery, low switching loss

· High surge overload rating of 25 Amperes peak

· Ideal for printed circuit board

 $\cdot$  High temperature soldering guaranteed:

260°C for 10 seconds

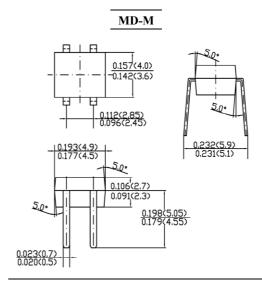
#### **MECHANICAL DATA**

Case: Molded plastic, MD-M

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202,

method 208 guaranteed Mounting position: Any Weight: 0.008ounce, 0.22gram



**Dimensions in inches and (millimeters)** 

### Maximum Ratings and Electrical Characteristics

Ratings at 25 ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	RMD1M	RMD2M	RMD3M	RMD4M	RMD5M	RMD6M	RMD7M	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current			•	•	•	•	•	•	
(see Fig. 1) on glass-epoxy P.C.B (Note 2)	I <sub>(AV)</sub> 0.5 0.8							Amp	
on aluminum substrate (Note 3)									
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I <sub>FSM</sub> 25							Amp	
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage	$V_{\mathrm{F}}$	1.25							Volts
at 0.4A DC and 25	V F								
Maximum Reverse Current at T <sub>A</sub> =25	$I_R$	5.0							uAmp
at Rated DC Blocking Voltage T <sub>A</sub> =125	1 <sub>R</sub>	500							
Typical Junction Capacitance (Note 1)	$C_{J}$	13							pF
Maximum Reverse Recovery Time (Note 4)	$T_{RR}$		1:	50		250	5	00	nS
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$	70						/W	
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	20						/W	
Operating and Storage Temperature Range	T <sub>J</sub> , Tstg	-55 to +150							

#### NOTES:

- 1- Measured at 1  $\ensuremath{\text{MH}_{\text{Z}}}$  and applied reverse voltage of 4.0 VDC.
- 2- On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3mm) pads
- 3- On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20mm) mounted on 0.05 x 0.05" (1.3 x 1.3mm) solder pad
- 4- Reverse Recovery Test Conditions:  $I_F$ =.5A ,  $I_R$ =1A ,  $I_{RR}$ =.25A.





#### RATINGS AND CHARACTERISTIC CURVES

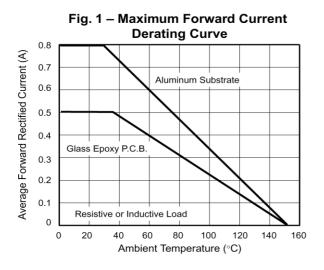


Fig. 2 - Maximum Non-Repetitive Peak **Forward Surge Current** 35 T<sub>A</sub> = 40°C Peak Forward Surge Current (A) 30 Single Half Sine-Wave (JEDEC Method) 25 20 f = 60Hz 15 10 5.0 0 10 100 Number of Cycles

Fig. 3 - Typical Instantaneous **Forward Characteristics** 10 Pulse Width = 300μs Instantaneous Forward Current (A) 1% Duty Cycle  $T_J = 150^{\circ}C$ = 25°C 0.2 0.4 0.6 0.8 1.0 1.2 1.4 Instantaneous Forward Voltage (V)

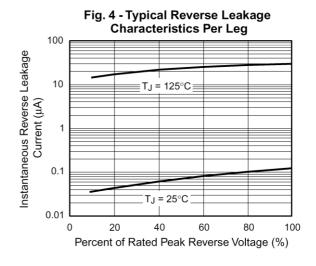


Fig. 5 - Typical Junction Capactitance Per Leg 30 T<sub>J</sub> = 25°C Junction Capacitance (pF) 25 f = 1 MHzVsig = 50mVp-p 20 15 10 5.0 0 0.1 10 100 200 Reverse Voltage (V)